

DPDT USB 2.0 High-Speed (480Mbps) and Mobile High-Definition Link (MHL) or Mobility Display Port (MyDP) Switch with ID Select and Flexible Power Control

Check for Samples: TS3USB3200

FEATURES

- V_{CC} Range: 2.7V to 4.3V
- Mobile High-definition Link (MHL) or Mobility Display Port (MyDP) Switch
 - Bandwidth (-3dB): 5.5 GHz
 - Ron (Typ): 5.7Ω
 - Con (Typ): 2.5pF
- USB Switch
 - Bandwidth (-3dB): 5.5 GHz
 - Ron (Typ): 4.6Ω
 - Con (Typ): 2.5pF
- Current Consumption: 40µA Typ
- Special Features
 - Flexible Power Control: Device can be Powered by V_{BUS} Without V_{CC} or by V_{CC} Alone
 - I_{OFF} Protection Prevents Current Leakage in Powered Down State (V_{CC} and V_{BUS}= 0 V)
 - 1.8-V Compatible Control Inputs (SEL1, SEL2, and PSEL)
 - Over-Voltage Tolerance (OVT) on all I/O
 Pins up to 5.5V Without External
 Components
- ESD Performance:
 - 3.5kV Human Body Model (A114B, Class II)
 - 1kV Charged Device Model (C101)
- Package:
 - 16-pin QFN Package (2.6 x 1.8 mm, 0.4 mm Pitch)

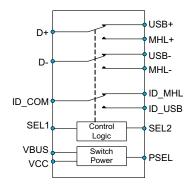
DESCRIPTION

The TS3USB3200 is a double-pole, double throw (DPDT) multiplexer that includes a high speed Mobile High-Definition Link (MHL) or Mobility Display Port (MyDP) switch and a USB 2.0 High-Speed (480Mbps) switch in the same package. Additionally included is a single-pole, double throw (SPDT) USB/MHL or MyDP ID switch for easy information control. These configurations allow the system designer to use a common USB or Mico-USB connector for both MHL/MyDP video signals and USB data.

The TS3USB3200 has a V_{CC} range of 2.7V to 4.3V and also has the option to be powered by V_{BUS} without V_{CC} . The device supports a over-voltage tolerance (OVT) feature which allows the I/O pins to withstand over-voltage conditions (up to 5.5V). The power-off protection feature forces all I/O pins to be in high impedance mode when power is not present. This allows full isolation of the signals lines without excessive leakage current. The select pins of TS3USB3200 are compatible with 1.8V control voltage, allowing them to be directly interfaced with the General Purpose I/O (GPIO) from a mobile processor.

The TS3USB3200 comes with a small 16-pin QFN package (2.6mm x 1.8mm in size), which makes it a perfect candidate for mobile applications.

SWITCH DIAGRAM



ORDERING INFORMATION

For package and ordering information, see the Package Option Addendum at the end of this document.

A

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

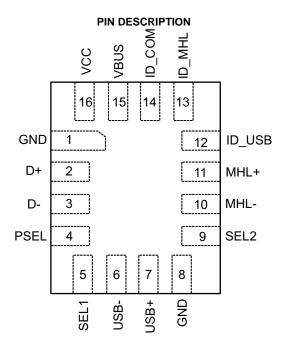
TS3USB3200



www.ti.com

SCDS333A – JUNE 2012 – REVISED JULY 2013

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.



PIN FUNCTIONS

	PIN		DESCRIPTION				
NO.	NAME	TYPE	DESCRIPTION				
1	GND	Ground	Ground				
2	D+	I/O	Data Switch Output (Differential +)				
3	D-	I/O	Data Switch Output (Differential –)				
4	PSEL	Input	Power Source Select Line				
5	SEL1	Input	Control Input Select Line 1				
6	USB-	I/O	USB Data (Differential –)				
7	USB+	I/O	USB Data (Differential +)				
8	GND	Ground	Ground				
9	SEL2	Input	Control Input Select Line 2				
10	MHL-	I/O	MHL Data (Differential-)				
11	MHL+	I/O	MHL Data (Differential +)				
12	ID_USB	I/O	ID Output for USB				
13	ID_MHL	I/O	ID Output for MHL				
14	ID_COM	I/O	ID Common				
15	V _{BUS}	Power	Alternative Device Power				
16	V _{CC}	Power	Power supply				

Copyright © 2012–2013, Texas Instruments Incorporated

SCDS333A – JUNE 2012–REVISED JULY 2013

V	V	PSEL ⁽¹⁾	POWER SOURCE
V _{cc}	V _{BUS}	FJEL	FOWER SOURCE
L	L	Х	No Power. All I/O in High-Z
L	Н	Х	V _{BUS}
Н	L	х	V _{CC}
Н	Н	L	V _{CC}
Н	Н	Н	V _{BUS}

Table 1. Function Table (Power Source)

(1) The PSEL pin has $6M\Omega$ weak pull-down resistor to GND to make its default value to be LOW.

SEL1 ⁽¹⁾	SEL2 ⁽¹⁾	CONNECTION	High-Z							
L	L	D+/D- to USB+/USB-, ID_COM to ID_USB	MHL+/MHL-, ID_MHL							
L	н	D+/D- to USB+/USB-, ID_COM to ID_MHL	MHL+/MHL-, ID_USB							
Н	L	D+/D- to MHL+/MHL-, ID_COM to ID_USB	USB+/USB-, ID_MHL							
Н	Н	D+/D- to MHL+/MHL-, ID_COM to ID_MHL	USB+/USB-, ID_USB							

Table 2. Function Table (Signal and ID Select)

(1) The SEL1 and SEL2 pins have $6M\Omega$ weak pull-down resistor to GND to make their default value to be LOW.

	MHL PATH	USB PATH	ID PATH
Number of switches	2	2	2
ON-state resistance (ron)	5.7 Ω	4.6 Ω	6.5 Ω
ON-state resistance match (Δr_{on})	<0.4 Ω	<0.4 Ω	<0.4 Ω
ON-state capacitance (C _{I/O} ,on)	2.5 pF	2.5 pF	3.0 pF
Bandwidth (BW)	5.5 GHz	5.5 GHz	2.2 GHz

Table 3. Summary of Typical Characteristics

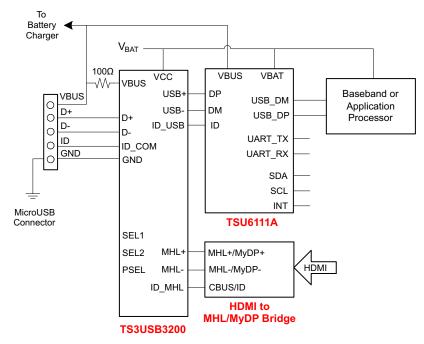
TEXAS INSTRUMENTS

www.ti.com

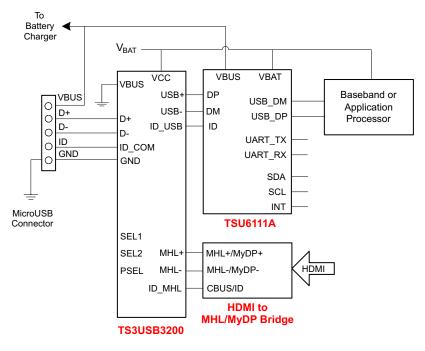
SCDS333A - JUNE 2012 - REVISED JULY 2013

TYPICAL APPLICATION

For Mobility Display Port Applications (MyDP) the signal voltage must be biased to ensure that the signal never exceeds the Recommended Operating conditions for the TS3USB3200. Namely the VIO should never operate outside the range of 0 V to 3.6 V. During manufacturing test when battery power is not available, the TS3USB3200 can be configured, as shown in the figure below, to be powered by VBUS through the microUSB connector. The control pins (SEL1 and SEL2) have built-in $6M\Omega$ pull-down resistors to ensure the USB paths are enabled for TS3USB3200 and allow connectivity to the TSU5611 USB accessory switch.



The TS3USB3200 can also be powered by the mobile device's standalone battery. The diagram below shows a typical implementation. The VBUS pin of the TS3USB3200 can simply be grounded under such conditions.





SCDS333A-JUNE 2012-REVISED JULY 2013

www.ti.com

ABSOLUTE MAXIMUM RATINGS⁽¹⁾⁽²⁾

over operating free-air temperature range (unless otherwise noted)

				MIN	MAX	UNIT
V _{CC} ,V _{BUS}	Supply voltage range ⁽³⁾	-0.3	5.5	V		
V _{I/O}	Input/Output DC voltage Range ⁽³⁾			-0.5	5.5	V
Ι _K	Input/Output port diode current	V _{I/O} < 0		-50		mA
VI	Digital input voltage range (SEL1, S	EL2, PSEL)		-0.3	5.5	V
I _{IK}	Digital logic input clamp current ⁽³⁾	V ₁ < 0		-50		mA
I _{CC}	Continuous current through V_{CC}				100	mA
I _{GND}	Continuous current through GND			-100		mA
T _{stg}	Storage temperature range			-65	150	°C

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

(2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

(3) All voltages are with respect to ground, unless otherwise specified.

PACKAGE THERMAL IMPEDANCE⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			TYP	UNIT
θ_{JA}	Package thermal impedance	RSV package	184	°C/W

(1) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
V _{CC}	Supply voltage range	2.7	4.3	V
V _{BUS}	V _{BUS} Supply voltage range	4.3	5.5	V
V _{I/O (USB)} V _{I/O (ID)}	Analog voltage range	0	3.6	V
V _{I/O (MHL)}		1.6	3.4	V
VI	Digital input voltage range (SEL1, SEL2, PSEL)	0	V_{CC}	V
T _{RAMP} (VCC)	Power supply ramp time requirement (V _{CC})	100	1000	µs/V
TRAMP (VBUS)	Power supply ramp time requirement (V _{BUS})	100	1000	µs/V
T _A	Operating free-air temperature	-40	85	°C

ELECTRICAL CHARACTERISTICS

 $T_A = -40^{\circ}$ C to 85°C, Typical values are at $V_{CC} = 3.3$ V, $T_A = 25^{\circ}$ C, (unless otherwise noted)

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT
MHL SWITC	н						
R _{ON}	ON-state resistance	$V_{CC} = 2.7V$	V _{I/O} = 1.6V, I _{ON} = -8mA		5.7		Ω
ΔR_{ON}	ON-state resistance match between + and –paths	V _{CC} = 2.7V	V _{I/O} = 1.6V, I _{ON} = -8mA		0.4		Ω
R _{ON (FLAT)}	ON-state resistance flatness	$V_{CC} = 2.7V$	$V_{I/O} = 1.6V$ to 3.4V, $I_{ON} = -8mA$		1		Ω
I _{OZ}	OFF leakage current	$V_{CC} = 4.3V$	Switch OFF, $V_{MHL+/MHL-} = 1.6V$ to 3.4V, $V_{D+/D-} = 0$ V	-2		2	μA
I _{OFF}	Power-off leakage current	$V_{CC} = 0V$	Switch ON or OFF, $V_{MHL+/MHL-} = 1.6V$ to 3.4V, $V_{D+/D-} = NC$	-10		10	μA
I _{ON}	ON leakage current	$V_{CC} = 4.3V$	Switch ON, $V_{MHL+/MHL-} = 1.6V$ to 3.4V, $V_{D+/D-} = NC$	-2		2	μA
USB SWITC	H						
R _{ON}	ON-state resistance	$V_{CC} = 2.7V$	$V_{I/O} = 0.4V, I_{ON} = -8mA$		4.6		Ω
ΔR_{ON}	ON-state resistance match between + and - paths	V _{CC} = 2.7V	V _{I/O} = 0.4V, I _{ON} = -8mA		0.4		Ω

Copyright © 2012-2013, Texas Instruments Incorporated

STRUMENTS

EXAS

ELECTRICAL CHARACTERISTICS (continued)

$T_A = -40^{\circ}$ C to 85°C, Typical values are at $V_{CC} = 3.3$ V, $T_A = 25^{\circ}$ C, (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
R _{ON (FLAT)}	ON-state resistance flatness	$V_{CC} = 2.7V$	$V_{I/O} = 0V$ to 0.4V, $I_{ON} = -8mA$		1		Ω
I _{oz}	OFF leakage current	$V_{CC} = 4.3V$	Switch OFF, $V_{USB+/USB-} = 0V$ to 4.3V, $V_{D+/D-} = 0V$	-2		2	μA
I _{OFF}	Power-off leakage current	$V_{CC} = 0V$	Switch ON or OFF, $V_{USB+/USB-} = 0V$ to 4.3V, $V_{D+/D-} = NC$	-10		10	μA
I _{ON}	ON leakage current	$V_{CC} = 4.3V$	Switch ON, $V_{USB+/USB-} = 0V$ to 4.3V, $V_{D+/D-} = NC$	-2		2	μA
ID SWITCH			-				
R _{ON}	ON-state resistance	$V_{CC} = 2.7V$	V _{I/O} = 3.3V, I _{ON} = -8mA		6.5		Ω
ΔR _{ON}	ON-state resistance match between + and - paths	$V_{CC} = 2.7V$	V _{I/O} = 3.3V, I _{ON} = -8mA		0.4		Ω
I _{oz}	OFF leakage current	$V_{CC} = 4.3V$	Switch OFF, $V_{ID_MHL/ID_USB} = 0V$ to 4.3V, $V_{ID_COM} = 0V$	-1		1	μA
I _{OFF}	Power-off leakage current	$V_{CC} = 0V$	Switch ON or OFF, $V_{ID_MHL/ID_USB} = 0V$ to 4.3V, $V_{ID_COM} = NC$	-10		10	μA
I _{ON}	ON leakage current	V _{CC} = 4.3V	Switch ON, $V_{ID_MHL/ID_USB} = 0V$ to 4.3V, $V_{ID_COM} = 0V$	-1		1	μA
DIGITAL CO	NTROL INPUTS (SEL1, SEL2, PS	EL)					
V _{IH}	Input logic high	$V_{CC} = 2.7V$ to 4	3V	1.3			V
V _{IL}	Input logic low	$V_{\rm CC} = 2.7 V$ to 4	3V			0.6	V
I _{IN}	Input leakage current	$V_{CC} = 4.3V, V_{1/C}$	= 0V to 4.3V, V _{IN} = 0 to 2V	-10		10	μA

DYNAMIC CHARACTERISTICS

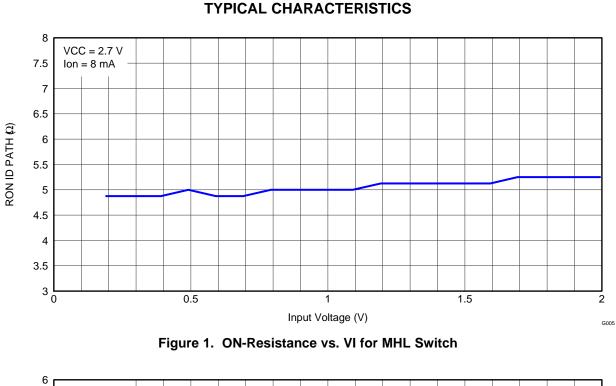
 $T_A = -40^{\circ}C$ to 85°C, Typical values are at V_{CC} = 3.3V, T_A =25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN TYP	MAX	UNIT	
MHL ⁽¹⁾ /USE	3/ ID SWITCH					
t _{pd}	Propagation Delay	$R_L = 50 \Omega, C_L = 5 pF$	V_{CC} = 2.7V to 4.3V	0.1		ns
t _{ON}	Turn-on time	$R_{L} = 50 \Omega, C_{L} = 5 pF$	$V_{CC} = 2.7V$ to $4.3V$		400	ns
t _{OFF}	Turn-off time	$R_L = 50 \Omega, C_L = 5 pF$	$V_{CC} = 2.7V$ to $4.3V$		400	ns
t _{SK(P)}	Skew of opposite transitions of same output	V _{CC} = 2.7 V or 3.3V	$V_{CC} = 2.7V \text{ to } 4.3V$	0.1	0.2	ns
C _{ON(MHL)}	MHL path ON capacitance	V_{CC} = 3.3 V, $V_{I/O}$ = 0 or 3.3 V, f = 240 MHz	Switch ON	1.6		pF
C _{ON(USB)}	USB path ON capacitance	V_{CC} = 3.3 V, $V_{I/O}$ = 0 or 3.3 V, f = 240 MHz	Switch ON	1.4		pF
C _{OFF(MHL)}	MHL path OFF capacitance	V_{CC} = 3.3 V, $V_{I/O}$ = 0 or 3.3 V, f = 240 MHz	Switch OFF	1.4		pF
C _{OFF(USB)}	USB path OFF capacitance	V_{CC} = 3.3 V, $V_{I/O}$ = 0 or 3.3 V, f = 240 MHz	Switch OFF	1.6		pF
CI	Digital input capacitance	$V_{CC} = 3.3 \text{ V}, \text{ V}_{I} = 0 \text{ or } 2\text{V}$		2.2		pF
O _{ISO}	OFF Isolation	$V_{CC} = 2.7 \text{ V to } 4.3 \text{ V}, \text{ R}_{L} = 50 \Omega,$ f = 240 MHz	Switch OFF	-37		dB
X _{TALK}	Crosstalk	$V_{CC} = 2.7 \text{ V to } 4.3 \text{ V}, \text{ R}_{L} = 50 \Omega,$ f = 240 MHz	Switch ON	-37		dB
BW _(MHL)	MHL path –3dB bandwidth	V_{CC} = 2.7 V to 4.3 V, R_L = 50 Ω	Switch ON	5.5		GHz
BW _(USB)	USB path –3dB bandwidth	V_{CC} = 2.7 V to 4.3 V, R_L = 50 Ω	Switch ON	5.5		GHz
BW _(ID)	ID path –3dB bandwidth	V_{CC} = 2.7 V to 4.3 V, R_L = 50 Ω	Switch ON	4.0		GHz
SUPPLY			<u>и</u>			
V _{BUS}	V _{BUS} Power supply voltage			4.3	5.5	V
V _{CC}	Power supply voltage			2.7	4.3	V
I _{CC}	Positive supply current	V_{CC} = 4.3 V, V_{IN} = V_{CC} or GND, $V_{I/O}$ = 0 V	Switch ON or OFF	40	70	μA
I _{CC, VBUS}	Positive supply current (V _{BUS} Mode)	V_{CC} = 0 V, V_{BUS} = 5.5 V, V_{IN} = V_{CC} or GND, $V_{I/O}$ = 0 V	Switch ON or OFF		50	μΑ

(1) Specified by Design



SCDS333A - JUNE 2012-REVISED JULY 2013



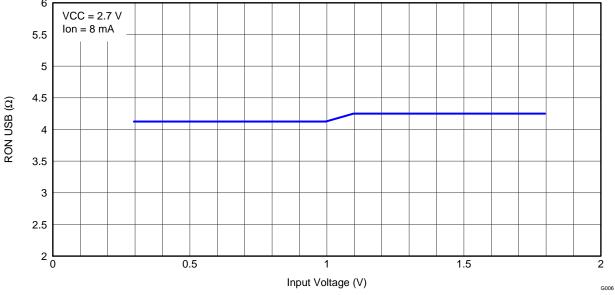


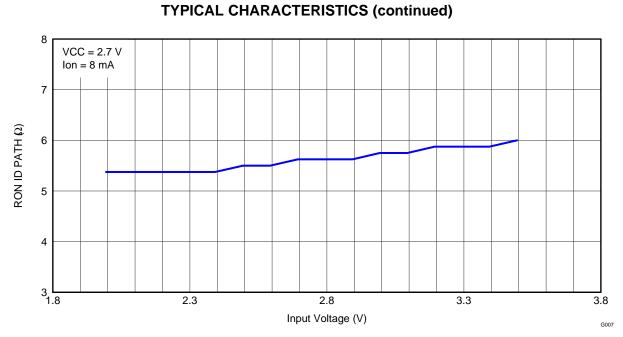
Figure 2. ON-Resistance vs. VI for USB Switch

EXAS

Texas Instruments

SCDS333A – JUNE 2012 – REVISED JULY 2013

www.ti.com





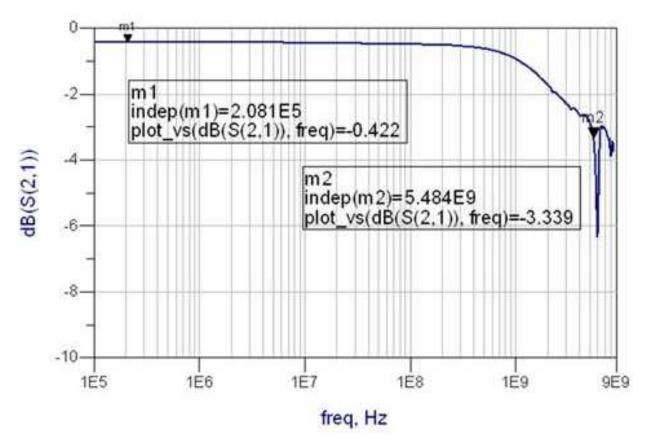


Figure 4. Gain vs. Frequency for MHL Switch



SCDS333A – JUNE 2012 – REVISED JULY 2013

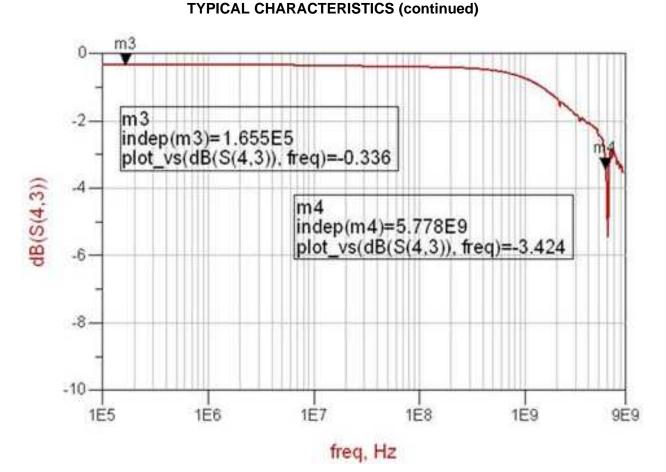
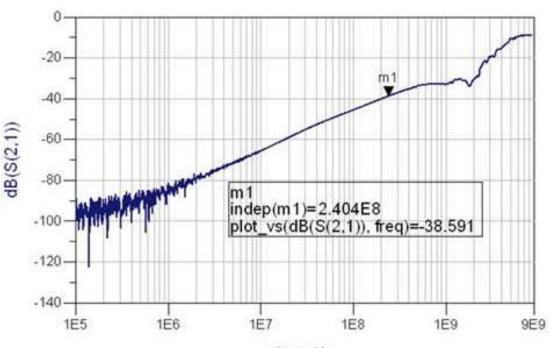


Figure 5. Gain vs. Frequency for USB Switch

Texas INSTRUMENTS

www.ti.com

SCDS333A-JUNE 2012-REVISED JULY 2013



freq, Hz



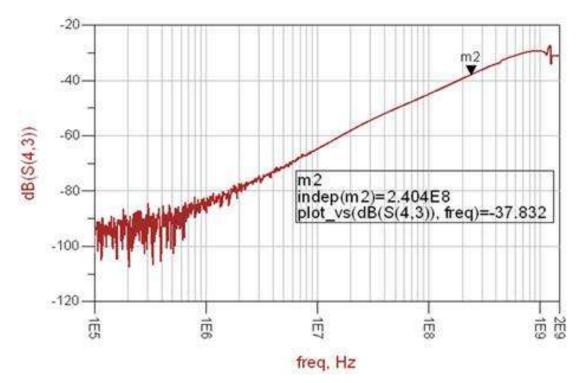
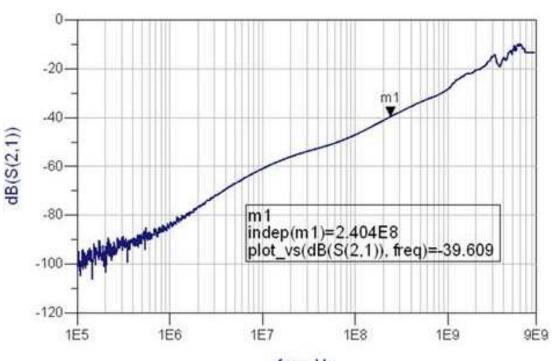


Figure 7. Off Isolation vs. Frequency for USB Path



SCDS333A -JUNE 2012-REVISED JULY 2013

www.ti.com



TYPICAL CHARACTERISTICS (continued)

freq, Hz



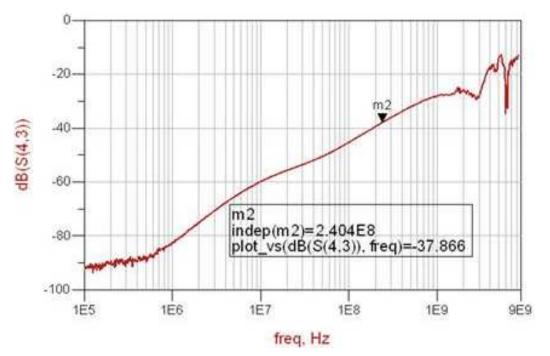


Figure 9. Cross talk vs. Frequency for USB Path

SCDS333A-JUNE 2012-REVISED JULY 2013

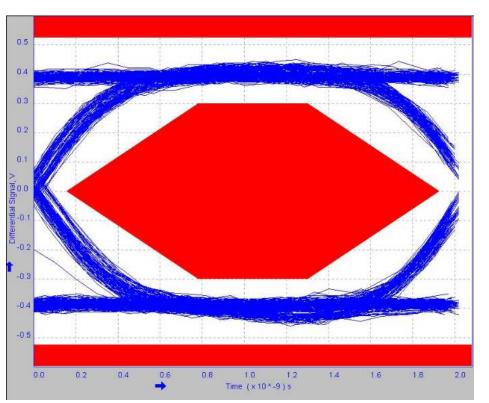
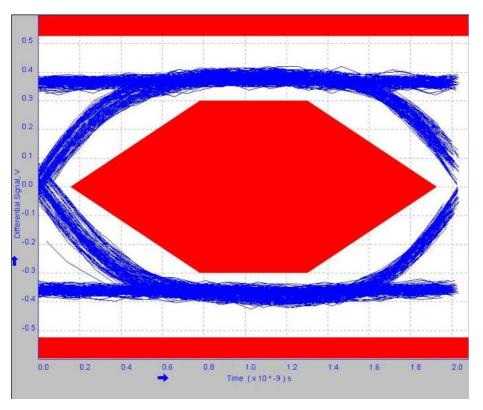
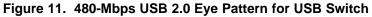




Figure 10. 480-Mbps USB 2.0 Eye Pattern with No Device







TS3USB3200

SCDS333A - JUNE 2012 - REVISED JULY 2013

www.ti.com

TYPICAL CHARACTERISTICS (continued)

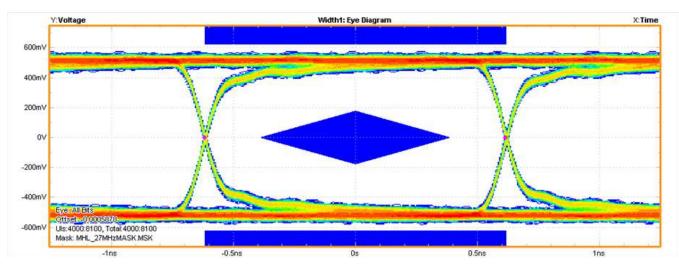


Figure 12. Eye Pattern: 0.7 Gbps MHL Eye Pattern for With No Device

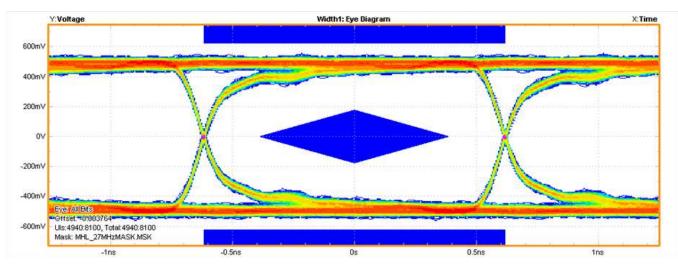
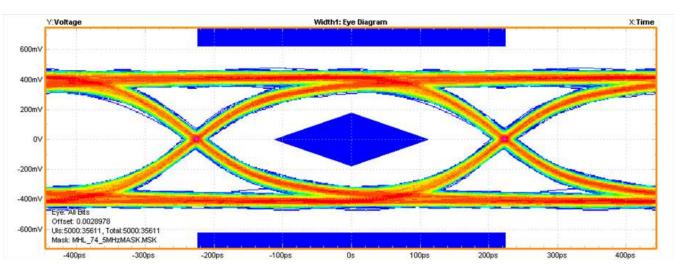


Figure 13. Eye Pattern: 0.7 Gbps MHL Eye Pattern for MHL Switch

TEXAS INSTRUMENTS

www.ti.com

SCDS333A - JUNE 2012 - REVISED JULY 2013



TYPICAL CHARACTERISTICS (continued)



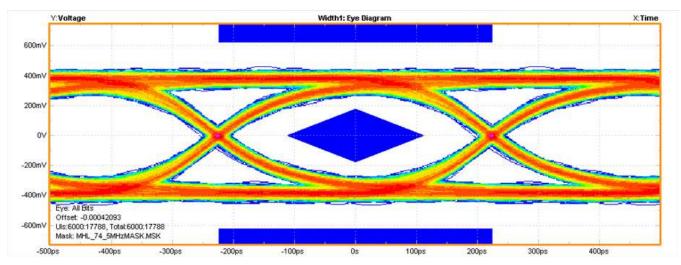


Figure 15. Eye Pattern: 2.2 Gbps MHL Eye Pattern for MHL Switch

14 Submit Documentation Feedback



TS3USB3200

SCDS333A - JUNE 2012 - REVISED JULY 2013

www.ti.com

TYPICAL CHARACTERISTICS (continued)

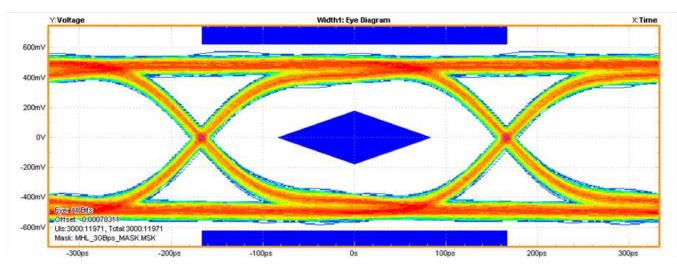


Figure 16. Eye Pattern: 3.0 Gbps MHL Eye Pattern for With No Device

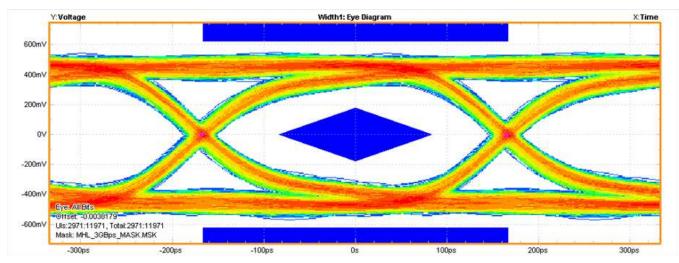


Figure 17. Eye Pattern: 3.0 Gbps MHL Eye Pattern for MHL Switch

SCDS333A - JUNE 2012 - REVISED JULY 2013

REVISION HISTORY

Cł	nanges from Original (June 2012) to Revision A Pa	age
•	Added Mobility Display Port (MyDP) option functionality.	1
•	Change Bandwidth for MHL and USB path to 5.5 GHz	. 3
•	Updated Typical Application diagrams.	. 4
•	Changed V _{I/O} MIN value from –0.3 to –0.5.	. 5

www.ti.com



9-Jul-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)		(3)		(4/5)	
TS3USB32008RSVR	ACTIVE	UQFN	RSV	16	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZTV	Samples
TS3USB3200RSVR	ACTIVE	UQFN	RSV	16	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZTO	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS3USB32008RSVR	UQFN	RSV	16	3000	180.0	9.5	2.1	2.9	0.75	4.0	8.0	Q1
TS3USB3200RSVR	UQFN	RSV	16	3000	180.0	12.4	2.1	2.9	0.75	4.0	12.0	Q1

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

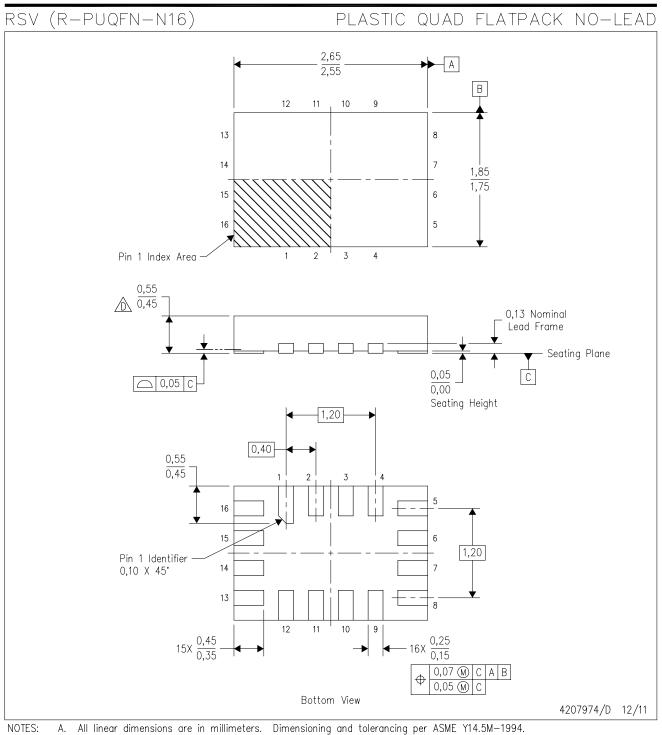
26-Oct-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS3USB32008RSVR	UQFN	RSV	16	3000	180.0	180.0	30.0
TS3USB3200RSVR	UQFN	RSV	16	3000	203.0	203.0	35.0

MECHANICAL DATA



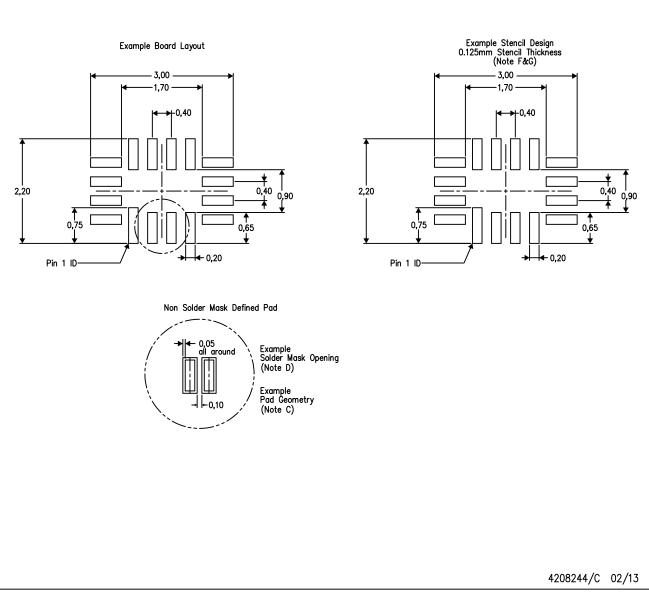
- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.

ightarrow This package complies to JEDEC MO-288 variation UFHE, except minimum package thickness.



RSV (R-PUQFN-N16)

PLASTIC QUAD FLATPACK NO-LEAD



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
- E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Side aperture dimensions over-print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products		Applications				
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive			
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications			
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers			
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps			
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy			
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial			
Interface	interface.ti.com	Medical	www.ti.com/medical			
Logic	logic.ti.com	Security	www.ti.com/security			
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense			
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video			
RFID	www.ti-rfid.com					
OMAP Applications Processors	www.ti.com/omap	TI E2E Community	e2e.ti.com			
Wireless Connectivity	www.ti.com/wirelessconnectivity					

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2013, Texas Instruments Incorporated